

Two-temperature (TTM) molecular dynamics

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TTM implementation in LAMMPS Paul Crozier, Carolyn Phillips

Cascade damage example Paul Crozier, Stephen Foiles, Ahmed Ismail







Electronic effects: two temperature model (TTM)

- Model radiation-excited carrier gas consisting of hot electrons and holes
- Provide a mechanism for energy exchange between radiation-excited carrier gas and atoms
- Conserves energy (electronic and atomic)
- Electron-ion energy transfer based on a Langevin thermostat
- Electronic temperature controlled by a heat diffusion equation

Duffy and Rutherford, *J. Phys. Condens. Matter* **2007** Rutherford and Duffy, *J. Phys. Condens. Matter* **2007**



TTM theory





 γ values are user-specified constants related to relaxation times (τ)



Energy transport in the electronic subsystem via the heat diffusion equation

$$C_{e} \frac{\partial T_{e}}{\partial t} = \nabla (\kappa_{e} \nabla T_{e}) - g_{p} (T_{e} - T_{a}) + g_{s} T_{a}'$$

- Electron temperature (T_e) varies locally.
- \bullet T_e is taken as an average in a spatial cell.
- Heat eqn is discretized and solved numerically.
- User supplies initial T_e values.
- LAMMPS keeps track of time evolution of T_e values.
- C_e and κ_e are user-specified constants.
- The T values and "coupling constants" (g_p and g_s) vary spatially and temporally.



Link between the electronic and atomic sub-systems

Energy loss of the atomic sub-system:

$$\Delta U_i = \mathbf{F}_i \cdot \mathbf{v}_i \Delta t = \gamma_i v_i^2 \Delta t \quad \Delta U_l = \Delta t \sum_{i \in J} \gamma_i v_i^2 = \Delta t \sum_{i \in J} \gamma_p v_i^2 + \Delta t \sum_{i' \in J} \gamma_s v_i'^2$$

Energy gain of the electronic sub-system:

$$\Delta U_{\rm eg} = g_{\rm p} T_{\rm a} \Delta V \Delta t + g_{\rm s} T_{\rm a}' \Delta V \Delta t.$$

Equate the two:

$$\sum_{i \in J} \gamma_{p} v_{i}^{2} = g_{p} T_{a} \Delta V$$
$$\sum_{i' \in J} \gamma_{s} v_{i}^{\prime 2} = g_{s} T_{a}^{\prime} \Delta V$$

And solve for the coupling "constants":

$$g_{\rm p} = \frac{3Nk_{\rm B}\gamma_{\rm p}}{\Delta Vm}$$
$$g_{\rm s} = \frac{3N'k_{\rm B}\gamma_{\rm s}}{\Delta Vm}.$$



Define the atomic T values:

$$\frac{3}{2}k_{\rm B}T_{\rm a} = 1/N \sum_{i \in J} \frac{1}{2}mv_i^2$$

 $\frac{3}{2}k_{\rm B}T_{\rm a}' = 1/N' \sum_{i' \in J} \frac{1}{2}mv_i'^2$

Implementation in LAMMPS

- Generalized for use with multiple atom types.
- T_e varies in time and in all three spatial dimensions.
- User supplies physical constants and initial T_e values.
- Reasonable energy conservation achieved.
- Models thermal conductivity and finite heat capacity of the electron subsystem.

Phillips and Crozier, J. Chem. Phys. 2009, 131, 074701



TTM input parameters (fix ttm)

- Electron specific heat*
- Electron density*
- Electron thermal conductivity
- Electron-ion interaction coefficient, γ_{p}^{*}
- Electron stopping friction coefficient, γ_s (SRIM tables, <u>www.srim.org</u>)
- Electron stopping critical velocity, v₀
- Number of electronic grid points
- Initial electron temperature

* DFT calculations can be used to estimate these values



Example: cascade damage simulation

Gadolinium pyrochlore waste form (Gd₂Zr₂O₇)

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Large initial velocity (10 keV) imparted to the primary knock-on atom (PKA) to simulate a radiation recoil event



Non-TTM results: Gd defects





Results of defect analysis



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Atomic and electronic temperature



PKA (U atom) displacement results



